



Shantou Huashan Electronic Devices Co.,Ltd.

NPN SILICON TRANSISTOR

H9018

APPLICATIONS

**AM/FM AMPLIFIER , LOCAL OSCILLATOR
OF FM/VHF TUNER**

ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ C$)

T_{stg} —Storage Temperature..... -55~150

T_j —Junction Temperature..... 150

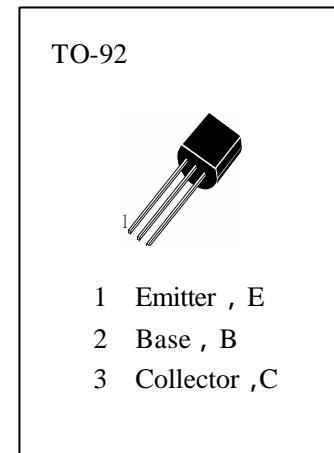
P_c —Collector Dissipation..... 400mW

V_{CBO} —Collector-Base Voltage..... 30V

V_{CEO} —Collector-Emitter Voltage..... 15V

V_{EBO} —Emitter-Base Voltage..... 5V

I_c —Collector Current..... 50mA



ELECTRICAL CHARACTERISTICS ($T_a=25^\circ C$)

Symbol	Characteristics	Min	Typ	Max	Unit	Test Conditions
I_{CBO}	Collector Cut-off Current			0.05	μA	$V_{CB}=12V, I_E=0$
HFE	DC Current Gain	54		198		$V_{CE}=5V, I_C=1mA$
$V_{CE(sat)}$	Collector- Emitter Saturation Voltage			0.5	V	$I_C=10mA, I_B=1mA$
$BVCBO$	Collector-Base Breakdown Voltage	30			V	$I_C=100 \mu A, I_E=0$
$BVCEO$	Collector-Emitter Breakdown Voltage	15			V	$I_C=1mA, I_B=0$
$BVEBO$	Emitter-Base Breakdown Voltage	5			V	$I_E=100 \mu A, I_C=0$
C_{ob}	Output Capacitance		1.3	1.7	pF	$V_{CB}=10V, I_E=0, f=1MHz$
f_T	Current Gain-Bandwidth Product	700			MHz	$V_{CE}=5V, I_C=5mA$

h_{FE} Classification

F

G

H

I

54—80

72—108

97—146

132—198



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Typical Characteristics

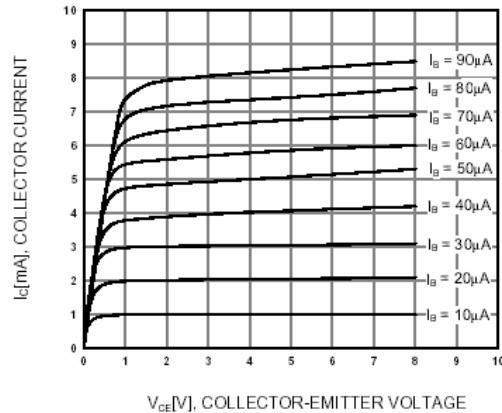


Figure 1. Static Characteristic

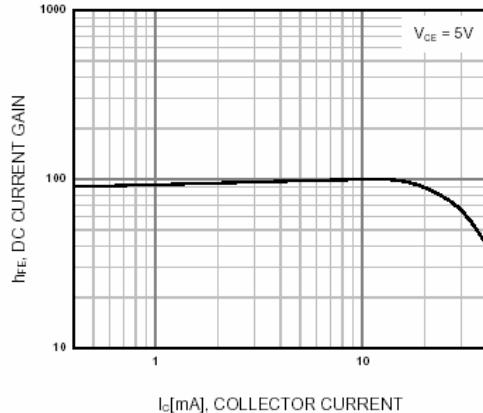


Figure 2. DC current Gain

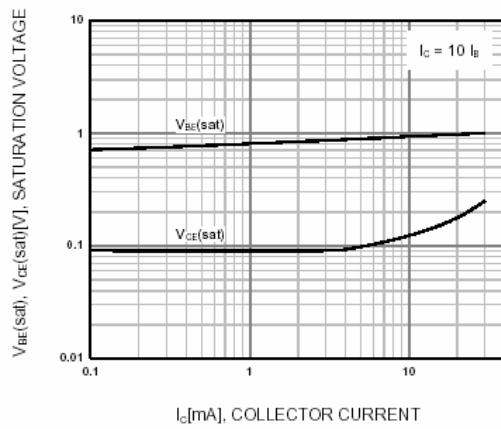


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

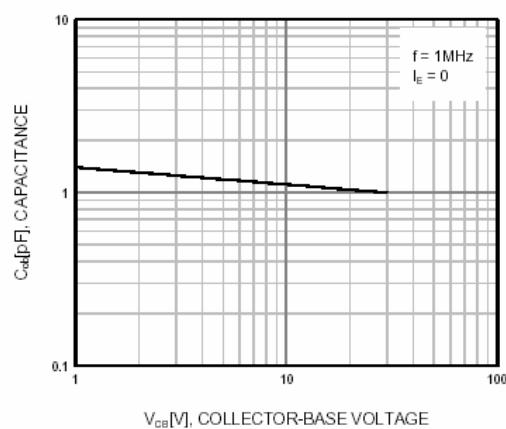


Figure 4. Output Capacitance

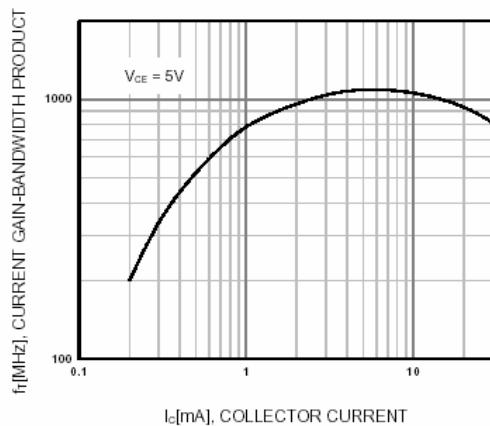


Figure 5. Current Gain Bandwidth Product